Electronic Visual Prosthesis Wentai Liu et al.



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- Evolution of the chips
- System block diagram
- Telemetry
- Retina-3.55 circuits



Abstract

- Visual Loss
 - Caused by RP and AMD
- Why IC?
 - Electrical stimulation may restore vision.



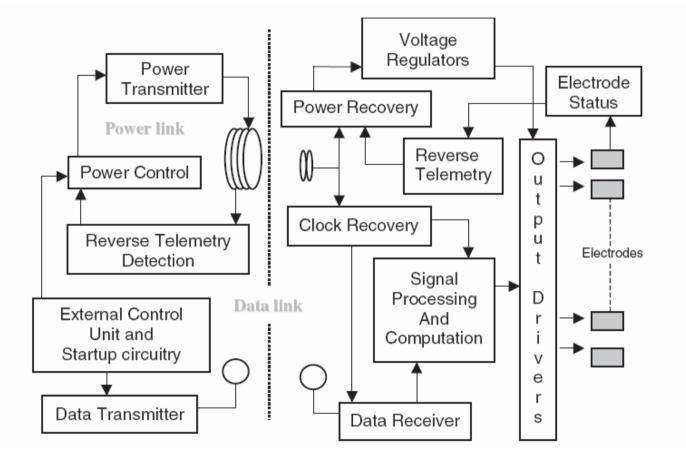
Evolution of the chips

Retinal chip	Salient features
Retina-1	5×5 Photo sensor array and current drivers; $2.0 \mu m$ CMOS technology
Retina-2	Photo sensors at the external side of the eye; 100 channels with 20 drivers (1:5 multiplexing); 2.0 µm CMOS technology
Retina-3	Additional circuitry for data recovery from PWM data link using ASK demodulator and DLL: AMI 1.2 µm technology
Retina-3.5/3.55	60 dedicated drivers; 2 independently programmable binary weighted DACs; error detection through CRC and check sum
Retina-4	Reduction of area using multibias DAC replacing the binary weighted DAC

FIG. 1. Evolution of the chips, Retina-1/2/3/3.55/4 (clockwise from top left).



System block diagram





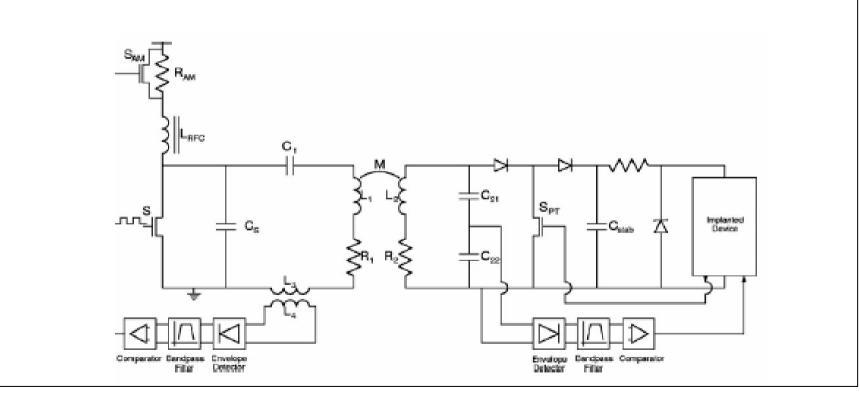
Telemetry

- Percutaneous connectors
 - Increasing the risk of infection.
- Solution
 - Partitioning the prosthesis into parts that are internal and external to the body.
 - Wireless link is a viable approach.
 - Magnetic coupled coils are used.



Frequency

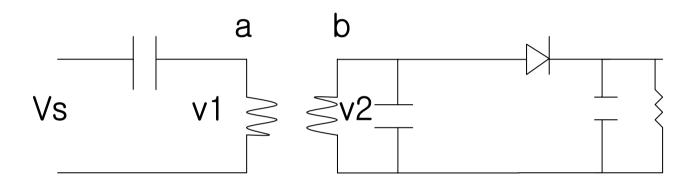
- Class E amp
- Resonant frequency





Forward telemetry

Ideal case -> K=1



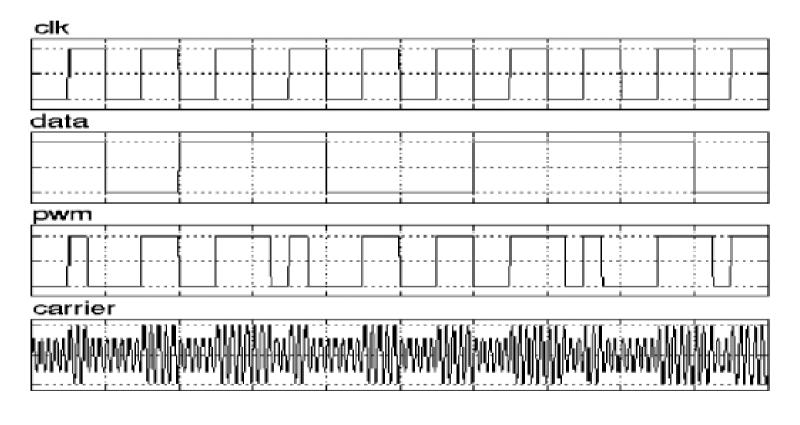
V1/a=V2/b

 $V2=(b/a)V1=Vs*[(a/b)*(1/jwc2)]/[(1/jwc1)+(a^2/b^2)*(1/jwc2)]$



Forward Encoding Method 1





Neural Prosthesis

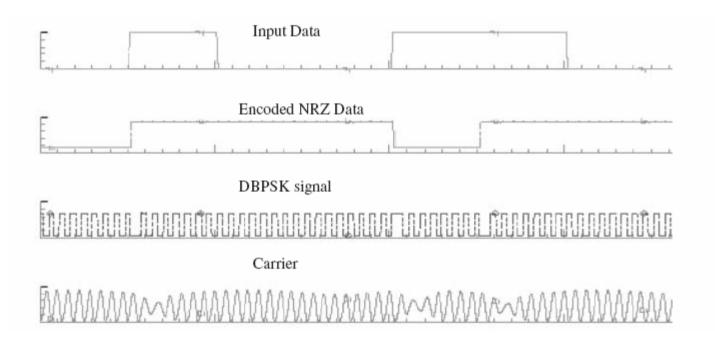
Differential binary phase shift keying

- Limitation of current technologies for the telemetry
 - Too slow to transmit enough data for high resolution.(1.5-2Mbps needed)
- This approach achieves higher data rates.
 - By allocation different freq for the power and forward telemetry data carriers.
 - The Carrier freq is 16MHz.



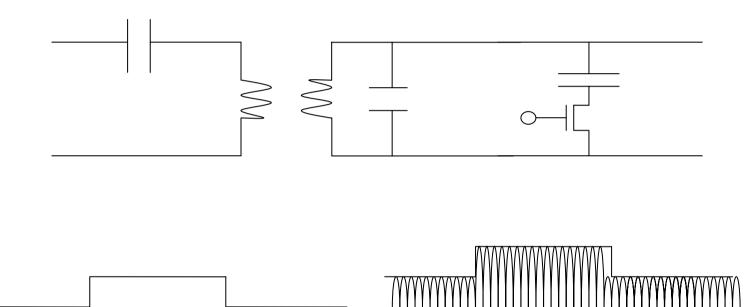
Forward Encoding Method 2

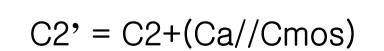
• DBPSK



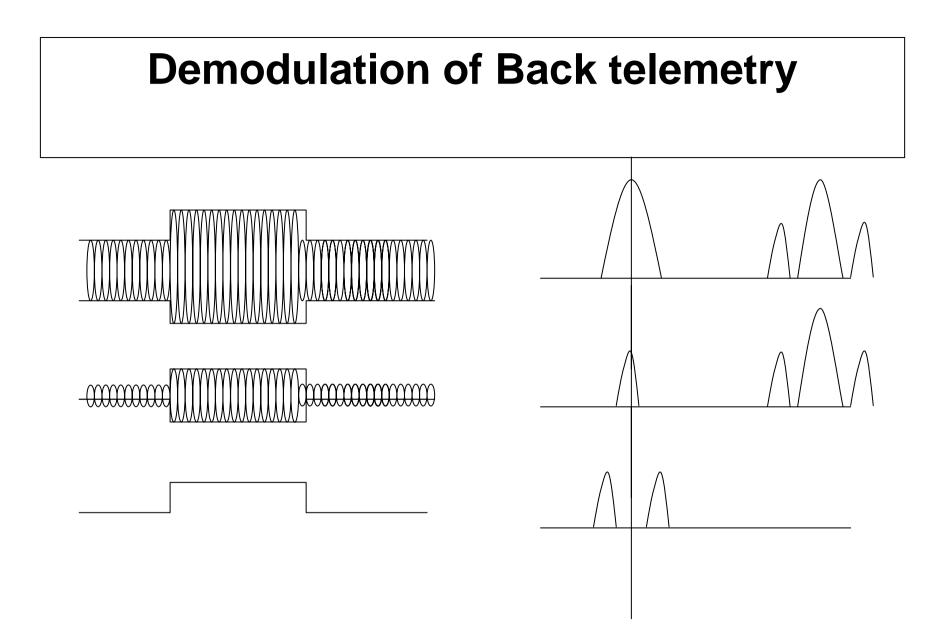


Modulation of Back telemetry











Power transmission

- Vs power
- Resonant freq matching (Class E amp, Inner, Outside circuit)
- Number Of Turn
- Condition
 - coil characteristic (material, parasitic R,C)
 - Skin



Retina-3.55 circuits

1.2-µm CMOS
5.5 mm x 5.25 mm
4.7 mm x 4.6 mm
60
60
1024
4 clock cycles (1/256 of frame time)
+7 V, -7 V
4 bits
200 μA, 400 μA, 600 μA
7.24%
16 µA/V
42 mW



Retina-3.55 photograph

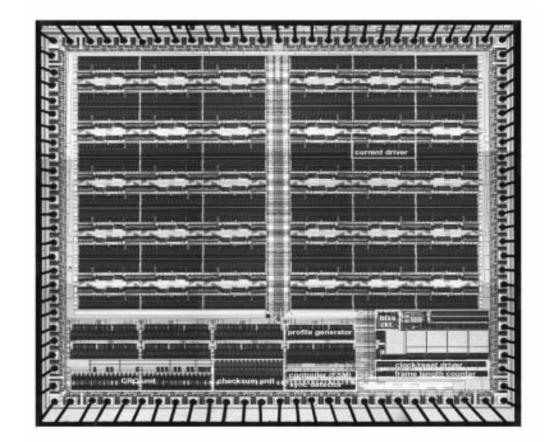


FIG. 8. Retina-3.55 photograph (4.6 mm × 4.7 mm).



Electronic Visual Prosthesis Part 2



Contents

- Introduction
- Specification of previous retinal Ics
- Retin-3.55
- Design of next generation retinal Ics
- Packaging issue
- Intraocular electromagnetic and thermal radiation
- Fabrication result
- Conclusion



Introduction

- Epiretinal approach for Retinitis pigmentosa (RP) and age-macular degeneration (AMD) patients
- Two parts system(external unit and internal unit)
- Stimulator chip with a small area and low power consumption



Specification of previous retinal ICs

Retinal chip	Salient features
Retina-1	5x5 photo sensor array and current drivers: 2.0um CMOS technology
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Retina-3.55 circuits (1)

Digital circuit feature

- Data input error detection
- Profile generation
- Data distribution to analog circuits
- Control logic circuits



Retina-3.55 circuits (2)

Communication protocol

- 1024-bits for one command
- 16-bit synchronization word
- Configuration packet
- 16-bit Data packet per one channel



Retina-3.55 circuits (3)

✤ Pulse profile

- 4-bits resolution
- 8-grobal programmable pulse timing references



Retina-3.55 circuits (4)

Error detection

- Due to telemetry link bit error
- 32-bit CRC
- 16-bit checksum error
- Remove packet or frame



Chip design for next generation retinal Ics(1)

- 32 x 32 (1000) stimulus matrix for face recognition
- Low power consumption
- Reliability of long life time
- TSMC 0.35 um technology
- 1: 8 output demultiplexing
- Single DAC
- Reducing headroom of current mirror



Chip design for next generation retinal Ics(2) * TCMS 0.35 um technology via AMI 1.2 um

- 1/3 size achieve 1/9 area
- 4 metal layers compared to 2 metal layers
 → higher circuit density
- Not much effective for analog circuit



Chip design for next generation retinal Ics(3) * 1:8 output demultipexing

- 1 driver and drive 8 pixels
- Each pixel is activated for 2 ms in a period of 16.67 ms
- 60 frames per second



Chip design for next generation retinal **Ics(4)**

✤ Single DAC

- **Reduces** area •
- Reduces any current amplitude mismatch lacksquare



Chip design for next generation retinal Ics(5)

- Reducing the headroom required by the current mirror can significantly decrease the power dissipated in the output driver stage
- Using active feedback current mirror

 \rightarrow voltage drop reach up to 12.5 V

TSMC 0.35 gate oxide breakdown at 5 V

• High voltage transistors can help it



Chip design for next generation retinal Ics(6)

• High voltage transistors problem

- Matching of the low voltage and high voltage transistors
- Large size of a high voltage device
- Large series resistance at the drain region
- Use Low voltage transistors and dynamically biasing the device



Packaging issue

✤ Hermetic seal

- Biological fluid in the eye
- Electrical isolation for the tissue around the chip



Intraocular electromagnetic and thermal radiation

heating effect

- The implant can change the steady state temperature of the eye
- Heat from absorption of electromagnetic radiation in tissues
- Heat from implanted chip
- Simulation to verify the safety of the effect



Fabricated result

Telemetry unit

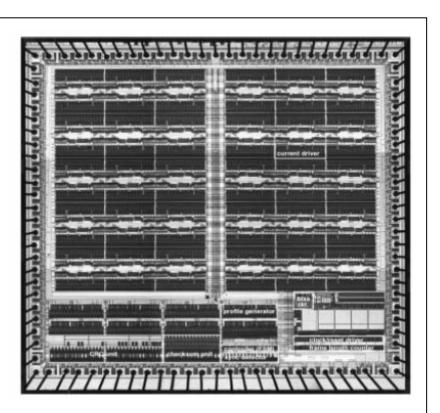
- Power supply rails of 7/14 V
- 25-250 kbps



Fabricated result

Stimulus chip

- Retina-3.55
- Size of 4.6 X 4.7 mm²





Conclusion

- Stimulus circuit for the retinal prosthesis
- Can be used to other implant system
- Study of nature require many fields such as biomedicine, chemistry, electronics and material science and so on

